Diode Semiconductor Device - Page 1 of 1



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Incl	osure Material:
Glas	SS
Ove	erall Length:
0.26	50 inches
Teri	minal Length:
1.00	00 inches
Ove	erall Diameter:
0.25	50 inches
Μοι	unting Method:
Terr	minal
Fea	tures Provided:
Her	metically sealed case
Sen	niconductor Material:
Silic	con
Volt	tage Rating In Volts Per Characteristic:
400	.0 reverse voltage, peak
Cur	rent Rating Per Characteristic:
3.00	amperes forward current, dc
Мах	kimum Operating Tempurature Per Measurement Point:
175	.0 degrees celsius ambient air
Teri	minal Type And Quantity:
2 ur	ninsulated wire lead
She	If Life:
N/a	
Uni	t Of Measure:
Den	nilitarization:
No	
Fiig	r.
A11	0a0